

L Number	Hits	Search Text	DB	Time stamp
1	640	257/77.ccls.	USPAT	2003/10/20 17:59
2	252	257/77.ccls. and diamond	USPAT	2003/10/20 18:00
3	180	(257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.) and diamond	USPAT	2003/10/20 18:02
4	57	257/713.ccls. and diamond	USPAT	2003/10/20 18:02
-	97	wafer and (diamond with (integrated adj circuit))	USPAT	2002/09/11 18:07
-	36	(wafer and (diamond with (integrated adj circuit))) and diamond.ti.	USPAT	2002/09/11 18:13
-	163	(diamond.ti. and diamond) and (heat adj sink)	USPAT	2002/09/11 18:14
-	43	(diamond.ti. and diamond) and (diamond near (heat adj sink))	USPAT	2002/09/11 18:14
-	99	438/105.ccls.	USPAT	2003/01/13 16:26
-	82	438/105.ccls. and diamond	USPAT	2002/09/11 20:08
-	14	(diamond and (integrated adj (circuit or circuits))) and (solid adj diamond)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/09/29 23:44
-	382	438/122.ccls.	USPAT	2002/09/30 02:49
-	27	438/122.ccls. and diamond	USPAT	2002/09/30 01:51
-	387	diamond and (monocrystalline adj silicon)	USPAT	2002/09/30 01:52
-	10	(diamond and (monocrystalline adj silicon)) and (heat adj sink)	USPAT	2002/09/30 01:51
-	1	(438/122.ccls. and diamond) and (monocrystalline adj silicon)	USPAT	2002/09/30 01:53
-	1	(438/122.ccls. and diamond) and (monocrystalline)	USPAT	2002/09/30 01:54
-	1	(monocrystalline adj silicon) and (diamond adj heat adj sink)	USPAT	2002/09/30 02:43
-	3	438/122.ccls. and (monocrystalline adj silicon)	USPAT	2003/10/20 17:58
-	113	(monocrystalline adj silicon) and (heat adj sink)	USPAT	2002/09/30 03:23
-	23	(flip adj chip) and (diamond with (heat adj sink))	USPAT	2002/09/30 03:24
-	46	(monocrystalline adj silicon) with diamond	USPAT	2002/09/30 03:42
-	101	438/105.ccls.	USPAT	2003/01/13 16:27
-	83	438/105.ccls. and diamond	USPAT	2003/01/13 16:48
-	596	257/77.ccls.	USPAT	2003/10/20 17:59
-	242	257/77.ccls. and diamond	USPAT	2003/01/13 16:53
-	151	(257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.) and diamond	USPAT	2003/10/20 18:00
-	32	((257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.) and diamond) and (CVD or (chemical adj vapor adj deposition))	USPAT	2003/01/13 17:11
-	15	(((257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.) and diamond) and (CVD or (chemical adj vapor adj deposition))) and (silicon with diamond)	USPAT	2003/01/14 13:54
-	414	(((semiconductor and diamond) and silicon) and (monocrystalline or monocrystal or (single adj crystal))) not (diamond adj saw)) and ((CVD or (chemical adj vapor adj deposit\$3)) with diamond)	USPAT	2003/01/14 15:58
-	179	117/929.ccls.	USPAT	2003/01/14 16:51
-	708	257/713.ccls.	USPAT	2003/01/14 19:31
-	56	257/713.ccls. and diamond	USPAT	2003/10/20 18:02
-	493	257/713.ccls. not (257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.)	USPAT	2003/01/14 19:31
-	31	(257/713.ccls. not (257/678.ccls. or 257/684.ccls. or 257/687.ccls. or 257/701.ccls. or 257/702.ccls. or 257/706.ccls. or 257/707.ccls. or 257/798.ccls.)) and diamond	USPAT	2003/01/14 19:31